

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			Vdss	20	V
Gate-Source Voltage		V _{GSS}	±8	V	
Continuous Drain Current (Note 5)	Steady State	T _A = +25°C T _A = +70°C	ID	4.2 3.2	А
Pulsed Drain Current (Note 6)			Ідм	30	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	0.78	W
Thermal Resistance, Junction to Ambient @T _A = +25°C	Reja	162	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

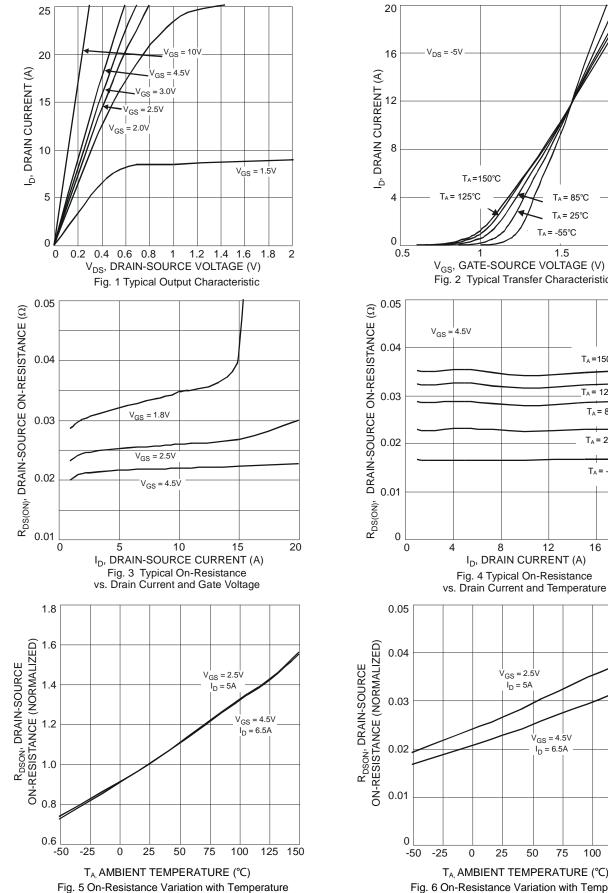
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	20			V	$V_{GS} = 0V, I_{D} = 250 \mu A$	
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	IDSS	_		1.0	μA	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	_	_	±100	nA	$V_{GS} = \pm 8V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)						·	
Gate Threshold Voltage	V _{GS(TH)}	0.5		0.9	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
	Rds(on)	_	19	25	mΩ	V _{GS} = 4.5V, I _D = 8.2A	
Static Drain-Source On-Resistance			22	29		V _{GS} = 2.5V, I _D = 3.3A	
			28	37		$V_{GS} = 1.8V, I_D = 2.0A$	
Forward Transfer Admittance	Y _{fs}	_	7		S	$V_{DS} = 10V, I_D = 4A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		829.9		pF		
Output Capacitance	Coss		85.3		pF	V _{DS} = 10V, V _{GS} = 0V f = 1.0MHz	
Reverse Transfer Capacitance	Crss		81.2		pF		
Total Gate Charge	Qg		9.6		nC		
Gate-Source Charge	Qgs	_	1.5		nC	V _{GS} = 4.5V, V _{DS} = 10V, I _D = 8.24	
Gate-Drain Charge	Q _{gd}	_	3.5		nC	1	
Turn-On Delay Time	tD(ON)	_	8.1		ns		
Turn-On Rise Time	tR	_	8.3		ns	V _{DD} = 10V, V _{GS} = 4.5V,	
Turn-Off Delay Time	tD(OFF)	_	40.1		ns	$R_L = 10\Omega, R_G = 6\Omega, I_D = 1A$	
Turn-Off Fall Time	tF	_	9.6		ns		

5. Device mounted on FR-4 PCB with 2oz. copper and test pulse width t \leq 10s. 6. Repetitive rating, pulse width limited by junction temperature. 7. Short duration pulse test used to minimize self-heating effect. Notes:

8. Guaranteed by design. Not subject to production testing.



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T_A = 85°C T_A = 25°C T_A = −55°C 1.5 2 V_{GS}, GATE-SOURCE VOLTAGE (V) Fig. 2 Typical Transfer Characteristic T_A=150°C T_A = 125°C T_A = 85°C T_A = 25°C T_A = -55°C 12 20 8 16 I_D, DRAIN CURRENT (A)

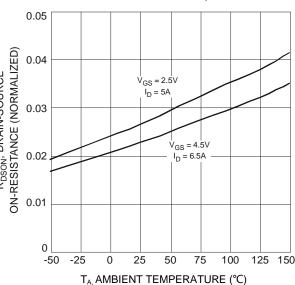
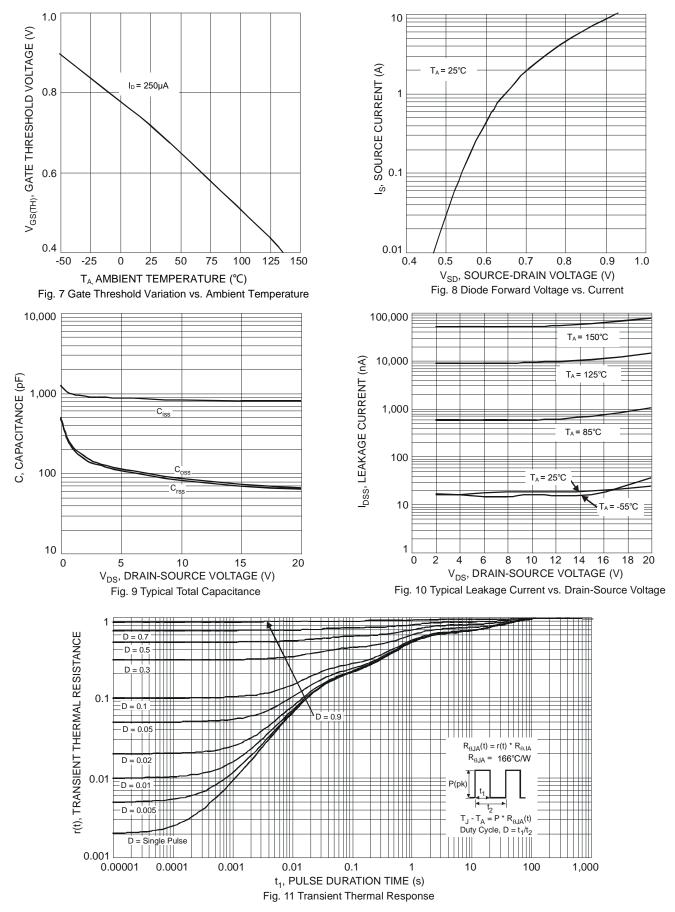


Fig. 6 On-Resistance Variation with Temperature

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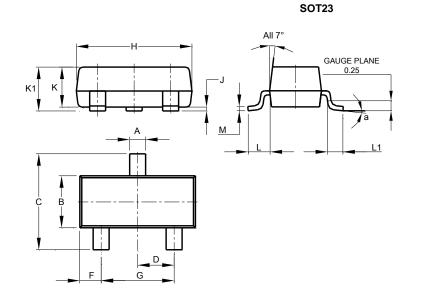
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Package Outline Dimensions

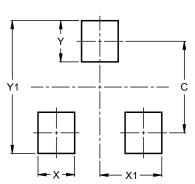
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SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
К	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
М	0.085	0.150	0.110		
а	0°	8°			
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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